


FORM 1449*
INFORMATION DISCLOSURE STATEMENT
IN AN APPLICATION
 (Use several sheets if necessary)

 Docket Number:
 50019.0272US01

 Application Number:
 10/786,846

Applicant: Qiang Luo

Filing Date: 2/25/2004

Group Art Unit: Not Yet Assigned

U.S. PATENT DOCUMENTS

EXAMINER INITIAL	DOCUMENT NO.	DATE	NAME	CLASS	SUBCLASS	FILING DATE IF APPROPRIATE
<i>QML</i>	5,841,158	11/24/1998	Merrill	257	233	
<i>QML</i>	5,841,176	11/24/1998	Merrill	257	446	

FOREIGN PATENT DOCUMENTS

	DOCUMENT NO.	DATE	COUNTRY	CLASS	SUBCLASS	TRANSLATION	
						YES	NO

OTHER DOCUMENTS (Including Author, Title, Date, Pertinent Pages, Etc.)

<i>QML</i>		Scott R. Stiffler, Jerry B. Lasky, Charles W. Koburger and Wayne S. Berry; <i>Oxidation-Induced Defect Generation in Advanced DRAM Structures</i> ; May 1990, Volume 37, Number 5, A Publication of the IEEE Electron Devices Society; pgs. 1253-1258
<i>QML</i>		Yukio Takano and Hirotsugu Kozuka; <i>Dislocation Generation due to Stress Induced by Oxidation in Si Grooves</i> ; Japanese Journal of Applied Physics Volume 22 (1983) Supplement 22-1; PGS. 553-556; Proceedings of the 14 th Conference (1982 International) on Solid State Devices, Tokyo 1982
<i>QML</i>		Hsiu-Yu Cheng and Ya-Chin King; <i>An Ultra-Low Dark Current CMOS Image Sensor Cell Using n+ Ring Reset</i> ; September 2002, Volume 23, Number 9, A Publication of the IEEE Electron Devices Society; pgs. 538-540
<i>QML</i>		Ikuko Inoue, Nagataka Tanaka, Hirofumi Yamashita, Tetsuya Yamaguchi, Hiroaki Ishiwata and Hisanori Ihara; <i>Low-Leakage-Current and Low-Operating-Voltage Buried Photodiode for a CMOS Image</i> ; January 2003, Volume 50, Number 1, 2003 IEEE; pgs. 43-47

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PATENT TRADEMARK OFFICE

EXAMINER

DATE CONSIDERED

12/27/05

EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609; draw line through citation if not in conformance and not considered. Include copy of this form for next communication to the Applicant.

FORM EKC-1449 If AFTER the later date of the first Office Action or 3 months from filing, use only with Rule 97(E) Certificate or Fee INFORMATION DISCLOSURE STATEMENT BY APPLICANT <small>(Use several sheets if necessary)</small>		Atty. Docket No. 89044PCW Customer No. 01333		Serial No. 10/786,846	
		Applicant: Qiang Luo			
		Filing Date 25 February 2004		Group 2811	

U.S. PATENT DOCUMENTS						
Examiner <small>Initial*</small>	DOCUMENT NUMBER	DATE	NAME	CLASS	SUBCLASS	FILING DATE <small>IF APPROPRIATE</small>
<i>[Signature]</i>	6,534,335 B1	03-18-2003	Rhodes et al.	—	—	
<i>[Signature]</i>	2001/0017382 A1	08-30-2001	Rhodes et al.	—	—	
<i>[Signature]</i>	6,495,391 B1	12-17-2002	Chan	—	—	

FOREIGN PATENT DOCUMENTS						
Examiner <small>Initial*</small>	DOCUMENT NUMBER	DATE	COUNTRY	CLASS	SUBCLASS	TRANSLATION <small>YES NO</small>

OTHER ART (Including Author, Title, Date, Pertinent Pages, Etc.)	
EXAMINER <i>[Signature]</i>	DATE CONSIDERED 12/27/05

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